MC14017B

Decade Counter

The MC14017B is a five−stage Johnson decade counter with built−in code converter. High speed operation and spike−free outputs are obtained by use of a Johnson decade counter design. The ten decoded outputs are normally low, and go high only at their appropriate decimal time period. The output changes occur on the positive−going edge of the clock pulse. This part can be used in frequency division applications as well as decade counter or decimal decode display applications.

Features

- Fully Static Operation
- DC Clock Input Circuit Allows Slow Rise Times
- Carry Out Output for Cascading
- Divide−by−N Counting
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low−Power TTL Loads or One Low−Power Schottky TTL Load Over the Rated Temperature Range
- Pin−for−Pin Replacement for CD4017B
- Triple Diode Protection on All Inputs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- This Device is Pb−Free and is RoHS Compliant

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SOIC−16
D SUFFIX
CASE 751B

PIN ASSIGNMENT

Q5	1●	16	V$_{DD}$
Q1	2	15	RESET
Q0	3	14	CLOCK
Q2	4	13	$\overline{CE}$
Q6	5	12	C$_{out}$
Q7	6	11	Q9
Q3	7	10	Q4
V$_{SS}$	8	9	Q8

MARKING DIAGRAM

16

14017BG
o   AWLYWW

1

A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G = Pb−Free Indicator

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

MAXIMUM RATINGS (Voltages Referenced to V$_{SS}$)

Symbol	Parameter	Value	Unit
V$_{DD}$	DC Supply Voltage Range	−0.5 to +18.0	V
V$_{in}$, V$_{out}$	Input or Output Voltage Range (DC or Transient)	−0.5 to V$_{DD}$ + 0.5	V
I$_{in}$, I$_{out}$	Input or Output Current (DC or Transient) per Pin	±10	mA
P$_D$	Power Dissipation, per Package (Note 1)	500	mW
T$_A$	Ambient Temperature Range	−55 to +125	°C
T$_{stg}$	Storage Temperature Range	−65 to +150	°C
T$_L$	Lead Temperature (8−Second Soldering)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
1. Temperature Derating: "D/DW" Packages: −7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high−impedance circuit. For proper operation, V$_{in}$ and V$_{out}$ should be constrained to the range V$_{SS}$ ≤ (V$_{in}$ or V$_{out}$) ≤ V$_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V$_{SS}$ or V$_{DD}$). Unused outputs must be left open.
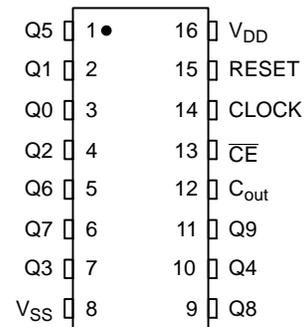
MC14017B

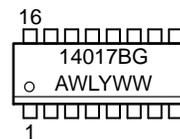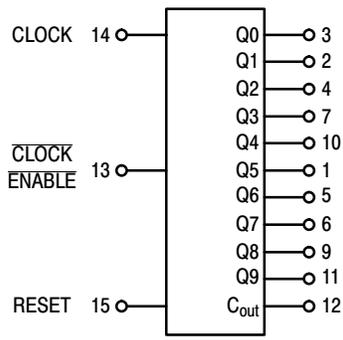## FUNCTIONAL TRUTH TABLE
(Positive Logic)

Clock	$\overline{\text{Clock}}$ $\overline{\text{Enable}}$	Reset	Decode Output=n
0	X	0	n
X	1	0	n
X	X	1	Q0
⌐	0	0	n+1
⌐	X	0	n
X	⌐	0	n
1	⌐	0	n+1

X = Don't Care. If n < 5 Carry = "1",
Otherwise = "0".

BLOCK DIAGRAM

V_{DD} = PIN 16
V_{SS} = PIN 8

LOGIC DIAGRAM
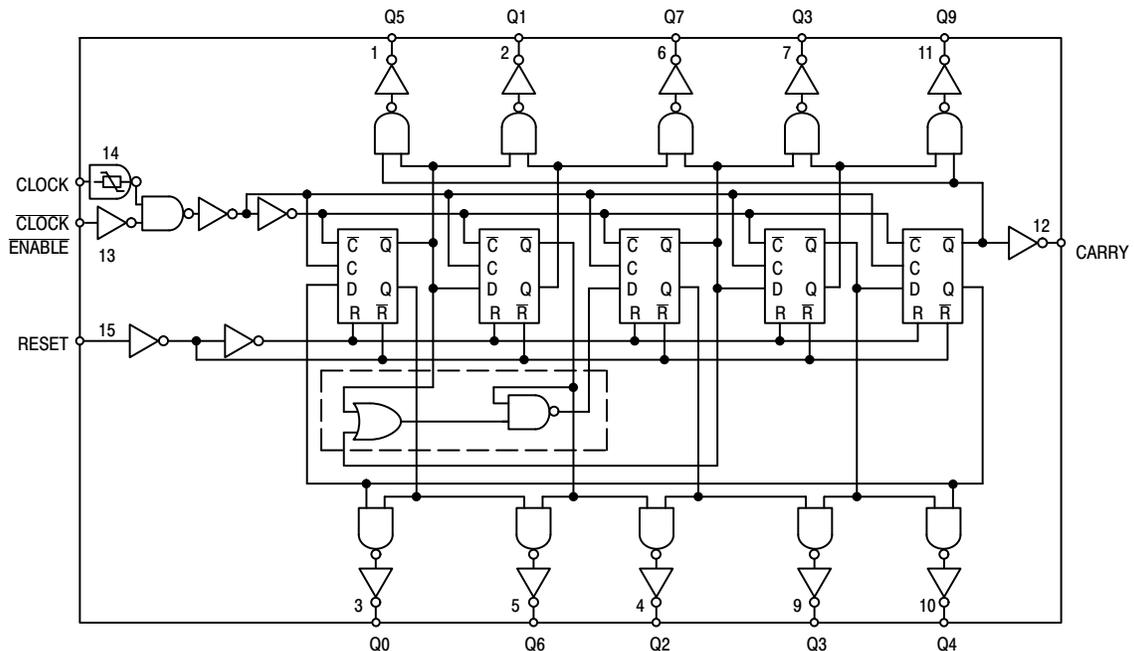
ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic		Symbol	V_{DD} Vdc	−55°C Min	−55°C Max	25°C Min	25°C Typ (Note 2)	25°C Max	125°C Min	125°C Max	Unit
Output Voltage "0" Level $V_{in} = V_{DD}$ or 0		V_{OL}	5.0	–	0.05	–	0	0.05	–	0.05	Vdc
			10	–	0.05	–	0	0.05	–	0.05	
			15	–	0.05	–	0	0.05	–	0.05	
"1" Level $V_{in} = 0$ or V_{DD}		V_{OH}	5.0	4.95	–	4.95	5.0	–	4.95	–	Vdc
			10	9.95	–	9.95	10	–	9.95	–	
			15	14.95	–	14.95	15	–	14.95	–	
Input Voltage "0" Level (V_O = 4.5 or 0.5 Vdc) (V_O = 9.0 or 1.0 Vdc) (V_O = 13.5 or 1.5 Vdc)		V_{IL}	5.0	–	1.5	–	2.25	1.5	–	1.5	Vdc
			10	–	3.0	–	4.50	3.0	–	3.0	
			15	–	4.0	–	6.75	4.0	–	4.0	
"1" Level (V_O = 0.5 or 4.5 Vdc) (V_O = 1.0 or 9.0 Vdc) (V_O = 1.5 or 13.5 Vdc)		V_{IH}	5.0	3.5	–	3.5	2.75	–	3.5	–	Vdc
			10	7.0	–	7.0	5.50	–	7.0	–	
			15	11	–	11	8.25	–	11	–	
Output Drive Current (V_{OH} = 2.5 Vdc) Source (V_{OH} = 4.6 Vdc) (V_{OH} = 9.5 Vdc) (V_{OH} = 13.5 Vdc)		I_{OH}	5.0	−3.0	–	−2.4	−4.2	–	−1.7	–	mAdc
			5.0	−0.64	–	−0.51	−0.88	–	−0.36	–	
			10	−1.6	–	−1.3	−2.25	–	−0.9	–	
			15	−4.2	–	−3.4	−8.8	–	−2.4	–	
(V_{OL} = 0.4 Vdc) Sink (V_{OL} = 0.5 Vdc) (V_{OL} = 1.5 Vdc)		I_{OL}	5.0	0.64	–	0.51	0.88	–	0.36	–	mAdc
			10	1.6	–	1.3	2.25	–	0.9	–	
			15	4.2	–	3.4	8.8	–	2.4	–	
Input Current		I_{in}	15	–	±0.1	–	±0.00001	±0.1	–	±1.0	µAdc
Input Capacitance (V_{in} = 0)		C_{in}	–	–	–	–	5.0	7.5	–	–	pF
Quiescent Current (Per Package)		I_{DD}	5.0	–	5.0	–	0.005	5.0	–	150	µAdc
			10	–	10	–	0.010	10	–	300	
			15	–	20	–	0.015	20	–	600	
Total Supply Current (Notes 3 & 4) (Dynamic plus Quiescent, Per Package) (C_L = 50 pF on all outputs, all buffers switching)		I_T	5.0	$I_T = (0.27\ \mu A/kHz)\ f + I_{DD}$							µAdc
			10	$I_T = (0.55\ \mu A/kHz)\ f + I_{DD}$							
			15	$I_T = (0.83\ \mu A/kHz)\ f + I_{DD}$							

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

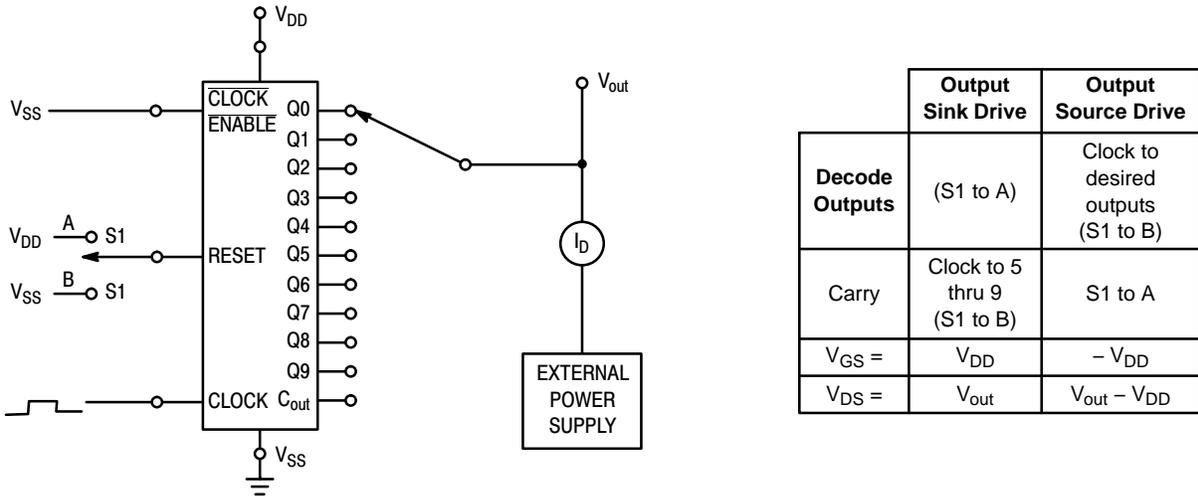3. The formulas given are for the typical characteristics only at 25°C.

4. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50\ pF) + (C_L − 50)\ Vfk$$

where: I_T is in µA (per package), C_L in pF, V = (V_{DD} − V_{SS}) in volts, f in kHz is input frequency, and k = 0.0011.

SWITCHING CHARACTERISTICS (Note 5) (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	V_{DD} Vdc	Min	Typ (Note 6)	Max	Unit
Output Rise and Fall Time t_{TLH}, t_{THL} = (1.5 ns/pF) C_L + 25 ns t_{TLH}, t_{THL} = (0.75 ns/pF) C_L + 12.5 ns t_{TLH}, t_{THL} = (0.55 ns/pF) C_L + 9.5 ns	t_{TLH}, t_{THL}	5.0 10 15	– – –	100 50 40	200 100 80	ns
Propagation Delay Time Reset to Decode Output t_{PLH}, t_{PHL} = (1.7 ns/pF) C_L + 415 ns t_{PLH}, t_{PHL} = (0.66 ns/PF) C_L + 197 ns t_{PLH}, t_{PHL} = (0.5 ns/pF) C_L + 150 ns	t_{PLH}, t_{PHL}	5.0 10 15	– – –	500 230 175	1000 460 350	ns
Propagation Delay Time Clock to C_{out} t_{PLH}, t_{PHL} = (1.7 ns/pF) C_L + 315 ns t_{PLH}, t_{PHL} = (0.66 ns/pF) C_L + 142 ns t_{PLH}, t_{PHL} = (0.5 ns/pF) C_L + 100 ns	t_{PLH}, t_{PHL}	5.0 10 15	– – –	400 175 125	800 350 250	ns
Propagation Delay Time Clock to Decode Output t_{PLH}, t_{PHL} = (1.7 ns/pF) C_L + 415 ns t_{PLH}, t_{PHL} = (0.66 ns/pF) C_L + 197 ns t_{PLH}, t_{PHL} = (0.5 ns/pF) C_L + 150 ns	t_{PLH}, t_{PHL}	5.0 10 15	– – –	500 230 175	1000 460 350	ns
Turn–Off Delay Time Reset to C_{out} t_{PLH} = (1.7 ns/pF) C_L + 315 ns t_{PLH} = (0.66 ns/pF) C_L + 142 ns t_{PLH} = (0.5 ns/pF) C_L + 100 ns	t_{PLH}	5.0 10 15	– – –	400 175 125	800 350 250	ns
Clock Pulse Width	$t_{w(H)}$	5.0 10 15	250 100 75	125 50 35	– – –	ns
Clock Frequency	f_{cl}	5.0 10 15	– – –	5.0 12 16	2.0 5.0 6.7	MHz
Reset Pulse Width	$t_{w(H)}$	5.0 10 15	500 250 190	250 125 95	– – –	ns
Reset Removal Time	t_{rem}	5.0 10 15	750 275 210	375 135 105	– – –	ns
Clock Input Rise and Fall Time	t_{TLH}, t_{THL}	5.0 10 15	No Limit			–
Clock Enable Setup Time	t_{su}	5.0 10 15	350 150 115	175 75 52	– – –	ns
Clock Enable Removal Time	t_{rem}	5.0 10 15	420 200 140	260 100 70	– – –	ns

5. The formulas given are for the typical characteristics only at 25°C.
6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

MC14017B

Figure 1. Typical Output Source and Output Sink Characteristics Test Circuit
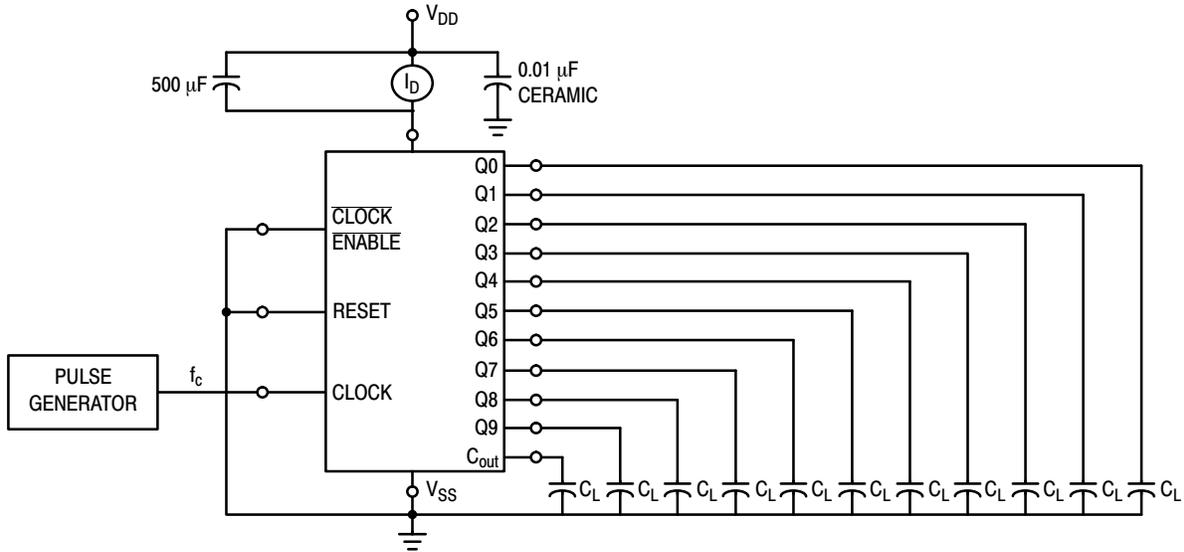
	Output Sink Drive	**Output Source Drive**
Decode Outputs	(S1 to A)	Clock to desired outputs (S1 to B)
Carry	Clock to 5 thru 9 (S1 to B)	S1 to A
V_{GS} =	V_{DD}	$- V_{DD}$
V_{DS} =	V_{out}	$V_{out} - V_{DD}$

Figure 2. Typical Power Dissipation Test Circuit

MC14017B

APPLICATIONS INFORMATION

Figure 3 shows a technique for extending the number of decoded output states for the MC14017B. Decoded outputs are sequential within each stage and from stage to stage, with no dead time (except propagation delay).
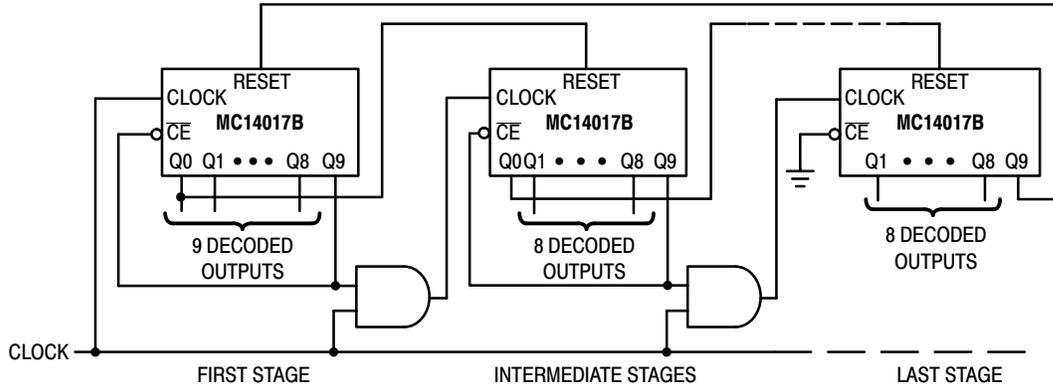
Figure 3. Counter Expansion
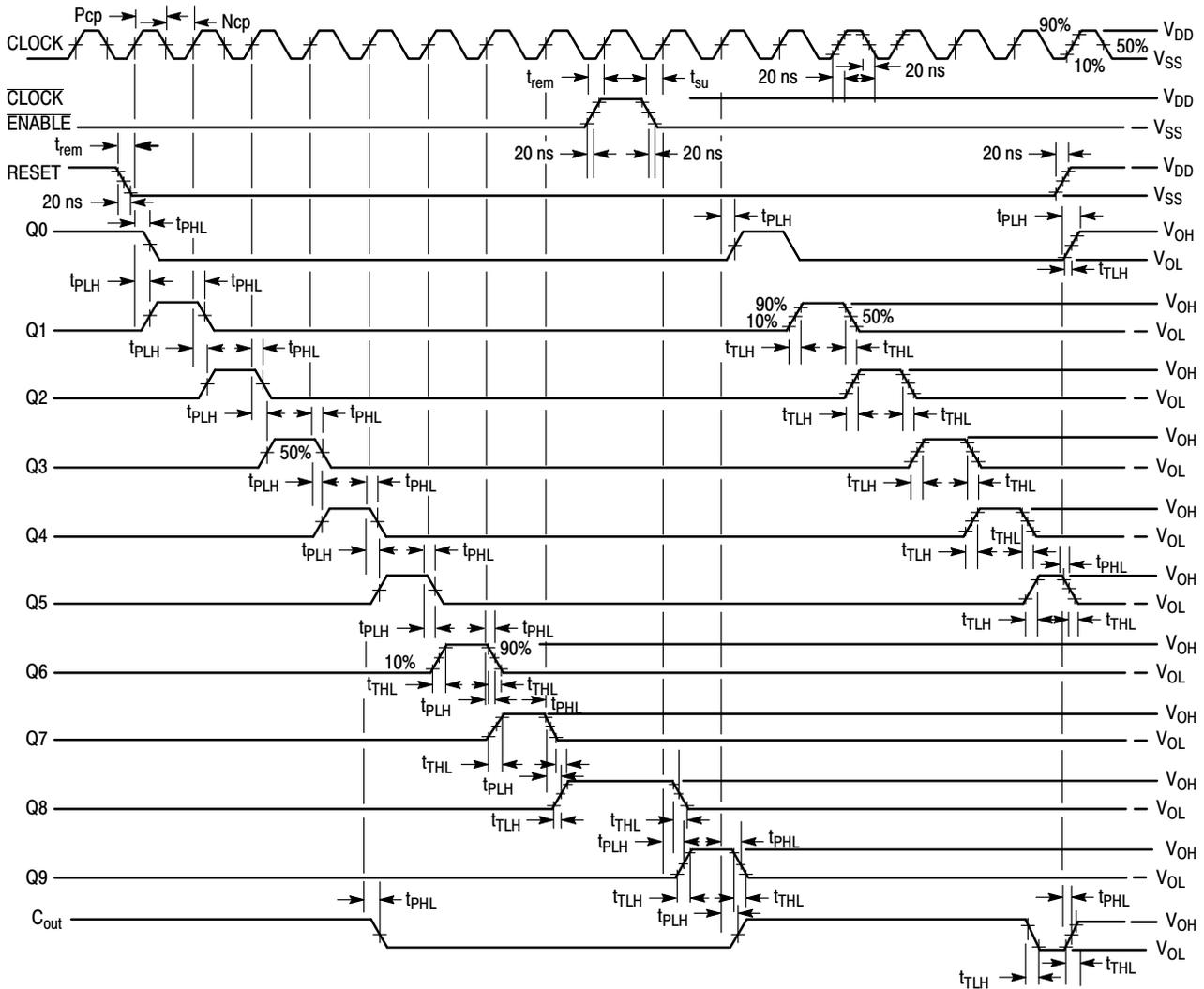
Figure 4. AC Measurement Definition and Functional Waveforms

ORDERING INFORMATION

Device	Package	Shipping†
MC14017BDG	SOIC−16 (Pb−Free)	48 Units / Rail
NLV14017BDG*	SOIC−16 (Pb−Free)	48 Units / Rail
MC14017BDR2G	SOIC−16 (Pb−Free)	2500 Units / Tape & Reel
NLV14017BDR2G*	SOIC−16 (Pb−Free)	2500 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable.

MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

ON Semiconductor®

SOIC−16
CASE 751B−05
ISSUE K

DATE 29 DEC 2006

SCALE 1:1
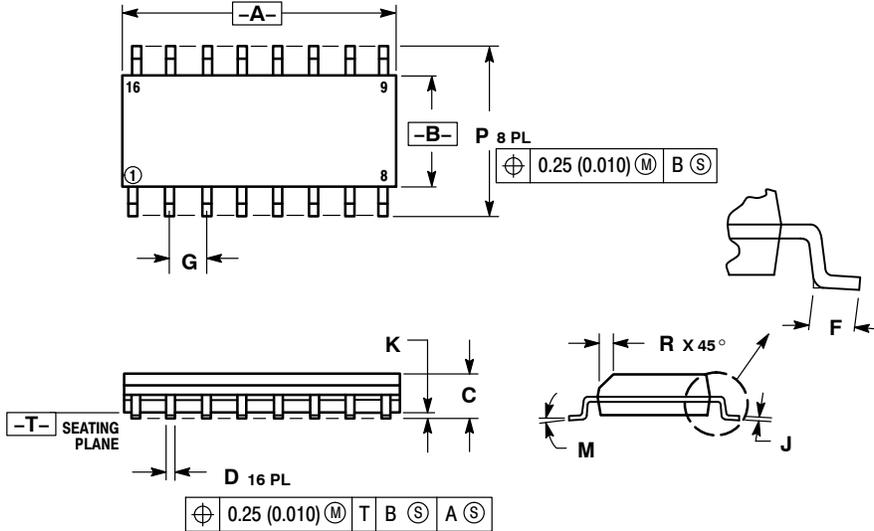
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

⊕ 0.25 (0.010) Ⓜ B Ⓢ

⊕ 0.25 (0.010) Ⓜ T B Ⓢ A Ⓢ

STYLE 1:
PIN 1. COLLECTOR
2. BASE
3. EMITTER
4. NO CONNECTION
5. EMITTER
6. BASE
7. COLLECTOR
8. COLLECTOR
9. BASE
10. EMITTER
11. NO CONNECTION
12. EMITTER
13. BASE
14. COLLECTOR
15. EMITTER
16. COLLECTOR

STYLE 2:
PIN 1. CATHODE
2. ANODE
3. NO CONNECTION
4. CATHODE
5. CATHODE
6. NO CONNECTION
7. ANODE
8. CATHODE
9. CATHODE
10. ANODE
11. NO CONNECTION
12. CATHODE
13. CATHODE
14. NO CONNECTION
15. ANODE
16. CATHODE

STYLE 3:
PIN 1. COLLECTOR, DYE #1
2. BASE, #1
3. EMITTER, #1
4. COLLECTOR, #1
5. COLLECTOR, #2
6. BASE, #2
7. EMITTER, #2
8. COLLECTOR, #2
9. COLLECTOR, #3
10. BASE, #3
11. EMITTER, #3
12. COLLECTOR, #3
13. COLLECTOR, #4
14. BASE, #4
15. EMITTER, #4
16. COLLECTOR, #4

STYLE 4:
PIN 1. COLLECTOR, DYE #1
2. COLLECTOR, #1
3. COLLECTOR, #2
4. COLLECTOR, #2
5. COLLECTOR, #3
6. COLLECTOR, #3
7. COLLECTOR, #4
8. COLLECTOR, #4
9. BASE, #4
10. EMITTER, #4
11. BASE, #3
12. EMITTER, #3
13. BASE, #2
14. EMITTER, #2
15. BASE, #1
16. EMITTER, #1

STYLE 5:
PIN 1. DRAIN, DYE #1
2. DRAIN, #1
3. DRAIN, #2
4. DRAIN, #2
5. DRAIN, #3
6. DRAIN, #3
7. DRAIN, #4
8. DRAIN, #4
9. GATE, #4
10. SOURCE, #4
11. GATE, #3
12. SOURCE, #3
13. GATE, #2
14. SOURCE, #2
15. GATE, #1
16. SOURCE, #1

STYLE 6:
PIN 1. CATHODE
2. CATHODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE
7. CATHODE
8. CATHODE
9. ANODE
10. ANODE
11. ANODE
12. ANODE
13. ANODE
14. ANODE
15. ANODE
16. ANODE

STYLE 7:
PIN 1. SOURCE N-CH
2. COMMON DRAIN (OUTPUT)
3. COMMON DRAIN (OUTPUT)
4. GATE P-CH
5. COMMON DRAIN (OUTPUT)
6. COMMON DRAIN (OUTPUT)
7. COMMON DRAIN (OUTPUT)
8. SOURCE P-CH
9. SOURCE P-CH
10. COMMON DRAIN (OUTPUT)
11. COMMON DRAIN (OUTPUT)
12. COMMON DRAIN (OUTPUT)
13. GATE N-CH
14. COMMON DRAIN (OUTPUT)
15. COMMON DRAIN (OUTPUT)
16. SOURCE N-CH

SOLDERING FOOTPRINT
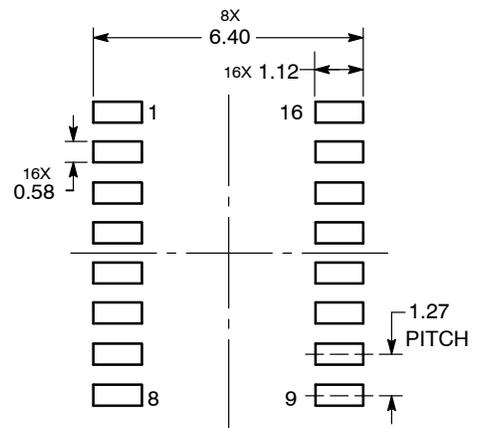
DIMENSIONS: MILLIMETERS

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DESCRIPTION:	SOIC−16		PAGE 1 OF 1

PUBLICATION ORDERING INFORMATION

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